Remarks

Claims 1-26 are presently pending. Claims 14-26 are withdrawn from consideration.

Claims 1-8 and 10-13 are rejected and claim 9 is objected to.

Claims 1, 2, and 5-6 are rejected under 35 U.S.C. § 103(a) as being unpatentable over Lee et al., "Super Self-Aligned Double-Gate (SSDG) MOSFET's Utilizing Oxidation Rate Difference and Selective Epitaxy," IEEE, pp. 3.5.1–3.5.4 in view of United States Patent No. 4,360,897 to Lehovec ("Lehovec").

Claims 1, 5, and 11 are rejected under 35 U.S.C. § 103(a) as being unpatentable over United States Patent No. 6,248,626 to Kumar et al. ("Kumar") in view of Lehovec.

Claims 5 and 10-13 are rejected under 35 U.S.C. § 103(a) as being unpatentable over United States Publication No. 2002/0093053 to Chan et al. in view of Kumar and Lehovec.

By this paper, independent claims 1 and 5 are amended to recite that the channel has a cross-sectional U-shape. Claim 9, that was objected to, is cancelled and its limitation included within claims 1 and 5. The Office Action states that the prior art of record fails to disclose a channel that has a cross-section U-shape. Accordingly, independent claims 1 and 5 represent patentable subject matter. Claims 2-4, 6-8, and 10-13 depend from their respective independent claims, include all limitations of their respective independent claims, and likewise represent patentable subject matter.

The Applicants believe the application is in condition for allowance and respectfully request the same. If there are any remaining issues of the pending claims that may be clarified by telephone, the Examiner is requested to call the undersigned.

Respectfully submitted,

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